AC6323A Datasheet

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AC6323A Features

High performance 32-bit RISC CPU

- RISC 32-bit CPU
- DC-96MHz operation
- 73KB data RAM
- 8KB I-cache 2way
- 1KB Rocache 1way
- 64 Vectored interrupts
- 8 Levels interrupt priority

Flexible I/O

- 17 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

Peripheral Feature

- One Full Speed USB OTG controller
- Four Multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex advanced UART(DMA)
- Three SPI interface supports host and device mode（DMA）
- One IIC interface supports host and device mode
- RTC,with alarm clock and time base to wake up the chip
- 16-bit PWM generator for motor driving
- Three IQ Encoder
- 8 channels 10-bit ADC
- 1 channel 8 levels Low Power Detector
- Embedded PMU support low power mode
- 2 Crystal Oscillator
- Watchdog
- Power-on reset

Bluetooth Feature

- CMOS single-chip fully-integrated radio and baseband
- Compliant with Bluetooth
- V5.0+BR+EDR+BLE specification
- Bluetooth Piconet and Scatternet support
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides +8dbm transmitting power
- Receiver with -92dBm sensitivity
- Support a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\gatt\rfcomm\sdp\l2cap profile

Power Supply

- LDOIN is 4.5V to 5.5V
- VBAT is 1.8V to 4.5V
- VDDIO is 1.8V to 3.4V

Packages

- QFN20

Temperature

- Operating temperature: -40℃ to +85℃
- Storage temperature: -65℃ to +150℃

1. Block Diagram

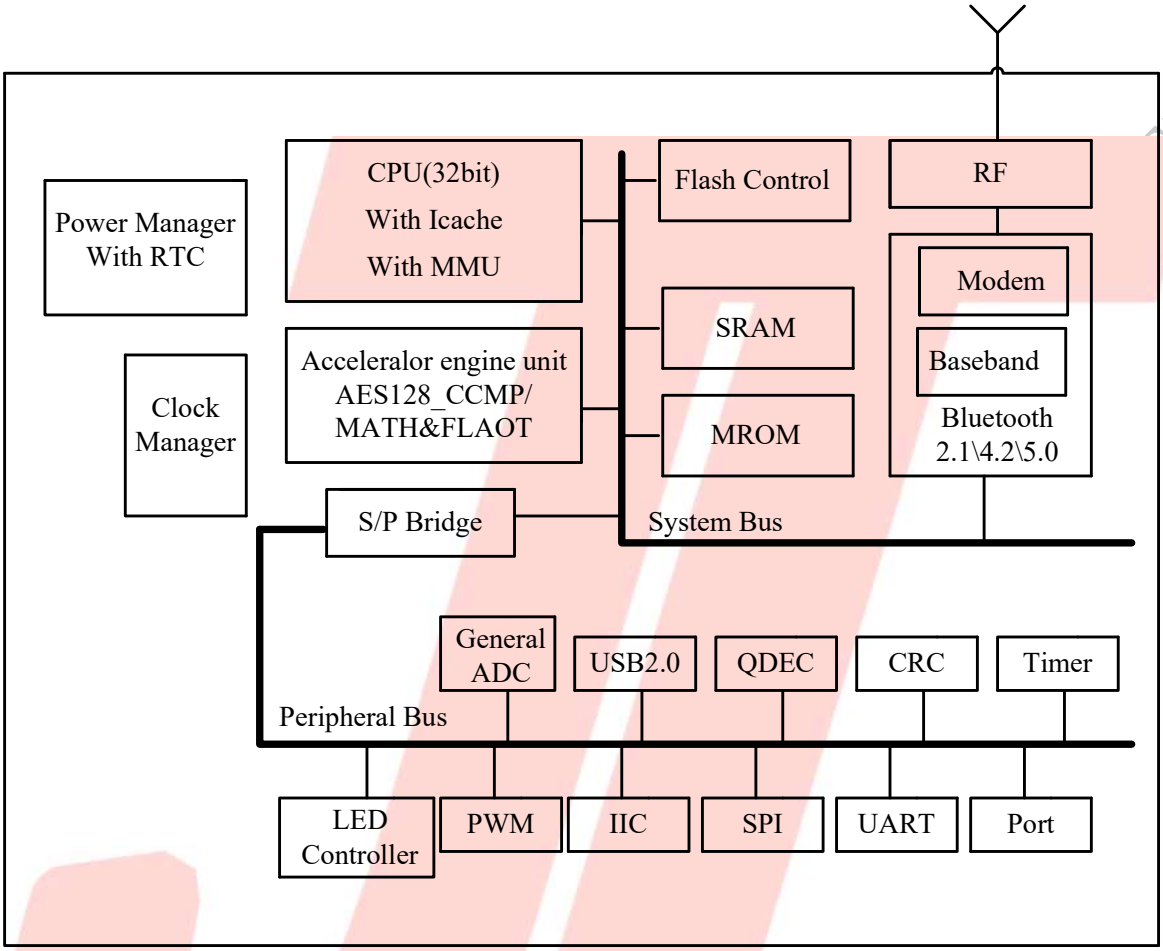


Figure 1-1 AC6323A_QFN20 Block Diagram

2. Pin Definition

2.1 Pin Assignment

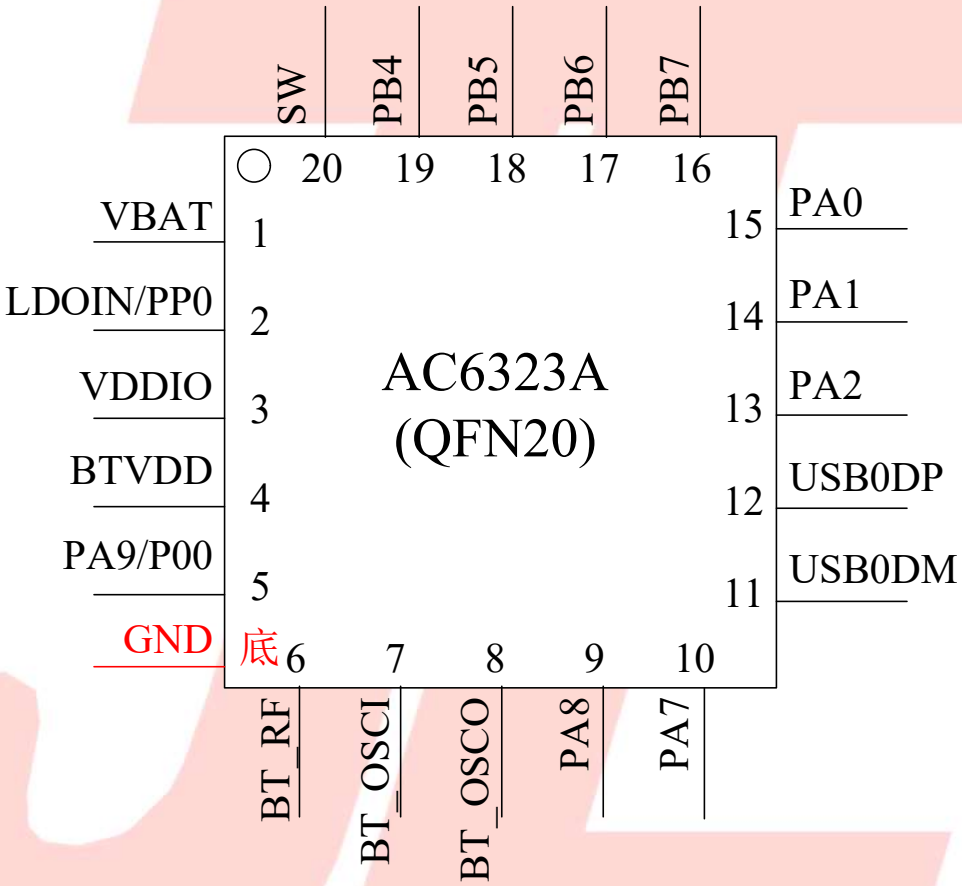


Figure 2-1 AC6323A_QFN20 Package Diagram

2.2 Pin Description

Table 2-1 AC6323A_QFN20 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	VBAT	P	LDO Power	-
2	LDOIN/PP0	P	Charge Power 5V	PWM3: Timer3 PWM Output; UART0_TXD: Uart0 Data Out(D); UART0_RXD: Uart0 Data In(D);
3	VDDIO	P	IO Power 3.3V	-
4	BTAVDD	P	Core Power 1.3V	-
5	PA9	I/O	GPIO (pull up)	Long Press Reset; ADC8: ADC Channel 8;
	P00	I/O	GPIO (High Voltage)	
6	BT_RF	-	RF Antenna	-
7	BTOSCI	I	BTOSCI	-
8	BTOSCO	O	BTOSCO	-
9	PA8	I/O	GPIO	TMR3: Timer3 Clock In; SPI1_DOA: SPI1 Data Out(A); IIC_SDA_C: IIC SDA(C); ADC4: ADC Channel 4; UART1_RXC: Uart1 Data In(C); PWMCH1L;
10	PA7	I/O	GPIO	TMR1: Timer1 Clock In; SPI1_CLKA: SPI1 Clock(A) ; IIC_SCL_C: IIC SCL(C); ADC3: ADC Channel 3; UART1_TXC: Uart1 Data Out(C); PWMCH1H;
11	USB0DM	I/O	GPIO (pull down)	SPI2_DOB: SPI2 Data Out(B); IIC_SDA_A: IIC SDA(A); ADC11: ADC Channel 11; UART1_RXD: Uart1 Data In(D);

12	USB0DP	I/O	GPIO (pull down)	SPI2_CLKB: SPI2 Clock(B); IIC_SCL_A: IIC SCL(A); ADC10: ADC Channel 10; UART1_TXD: Uart1 Data Out(D);
13	PA2	I/O	GPIO	CAP3: Timer3 Capture; Q-decoder0_1; UART0_RXC: Uart0 Data In(C); UART1_RTS;
14	PA1	I/O	GPIO	PWM0: Timer0 PWM Output; Q-decoder0_0; ADC0: ADC Channel 0; UART0_TXC: Uart0 Data Out(C); UART1_CTS;
15	PA0	I/O	GPIO (High Voltage)	CLKOUT1; UART2_TXB: Uart2 Data Out(B); UART2_RXB: Uart2 Data In(B); PWMCH0H;
16	PB7	I/O	GPIO (High Voltage)	SPI2_DOA: SPI2 Data Out(A); UART2_RXC: Uart2 Data In(C);
17	PB6	I/O	GPIO	SPI2_CLKA: SPI2 Clock(A) ; ADC12: ADC Channel 12; UART2_TXC: Uart2 Data Out(C); TMR3CK;
18	PB5	I/O	GPIO (High Voltage)	SPI2_DIA: SPI2 Data In(A); UART1_RXA: Uart1 Data In(A); PWMCH3L;
19	PB4	I/O	GPIO	TMR2: Timer2 Clock In; Q-decoder2_0; SPI1_DIB: SPI1 Data In(B); ADC9: ADC Channel 9; UAR1_TXA: Uart1 Data Out(A); PWMCH3H;
20	SW	P	DC-DC Switch Pin	-
Substrate		P	GND	-

3. Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	℃
Tstg	Storage temperature	-65	+150	℃
VBAT	Supply Voltage	-0.3	4.5	V
LDO_IN	Charge Input Voltage	-0.3	6	V
$V_{3.3IO}$	3.3V IO Input Voltage	-0.3	3.6	V

Note : The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 Recommended Operating Conditions

Table 3-2

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
VBAT	Voltage Input	1.8	3.7	4.5	V	_
LDOIN	Voltage Input	4.5	5.0	5.5	V	_
VDDIO	Voltage output	1.8	3.0	3.4	V	VBAT= 4.2V, 60mA loading
BTAVDD	Voltage output	1	1.3	1.4	V	DC-DC mode: 40mA loading
IL3.3	Loading current	_	_	60	mA	VBAT = 4.2V

3.3 Battery Charge

Table 3-3

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
LDO_IN	Charge Input Voltage	4.5	5	5.5	V	_
V_{Charge}	Charge Voltage	4.15	4.2	4.25	V	_
I_{Charge}	Charge Current	20		200	mA	Charge current at fast charge mode
I_{Trikl}	Trickle Charge Current	20	45	70	mA	V_{BAT} <V_{Trikl}

3.4 IO Input/Output Electrical Logical Characteristics

Table 3-4

IO input characteristics						
Symbol	**Parameter**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
V_{IL}	Low-Level Input Voltage	-0.3	–	0.3* VDDIO	V	VDDIO = 3.3V
V_{IH}	High-Level Input Voltage	0.7* VDDIO	–	VDDIO+0.3	V	VDDIO = 3.3V
IO output characteristics						
V_{OL}	Low-Level Output Voltage	–	–	0.33	V	VDDIO = 3.3V
V_{OH}	High-Level Output Voltage	2.7	–	–	V	VDDIO = 3.3V

3.5 Internal Resistor Characteristics

Table 3-5

Port	**Drive Strength**	**Internal Pull-Up Resistor**	**Internal Pull-Down Resistor**	**Comment**
PA1-PA9, PB4,PB6,	drive_select[11] 24mA drive_select[10] 24mA (with 120ohm res) drive_select[01] 8mA drive_select[00] 8mA (with 120ohm res)	10K	10K	1. PA9&PB2 default pull up 2. USB0DM&USB0DP default pull down 3. Internal pull-up/pull-down resistance | accuracy ±20% 4.PA0,PB5,PB7 can pull-up resistance to 5V
PA0,PB5, PB7	8mA	10K	10K	
USB0DP	4mA	1.5K	15K	
USB0DM	4mA	180K	15K	

3.6 BT Characteristics

3.6.1 Transmitter

Basic Data Rate **Table 3-6**

Parameter		**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
RF Transmit Power			4	6	dBm	25℃, Power Supply VBAT=5V
RF Power Control Range			20		dB	
20dB Bandwidth			950		KHz	
Adjacent Channel	+2MHz		-40		dBm	

	-2MHz		-38		dBm	
	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

Enhanced Data Rate **Table 3-7**

Parameter		Min	Typ	Max	Unit	Test Conditions
Relative Power			-1		dB	
π/4 DQPSK Modulation Accuracy	DEVM RMS		7		%	25℃, Power Supply VBAT=5V 2441MHz
	DEVM 99%		12		%	
	DEVM Peak		17		%	
Adjacent Channel Transmit Power	+2MHz		-40		dBm	
	-2MHz		-38		dBm	
	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

3.6.2 Receiver

Basic Data Rate **Table 3-8**

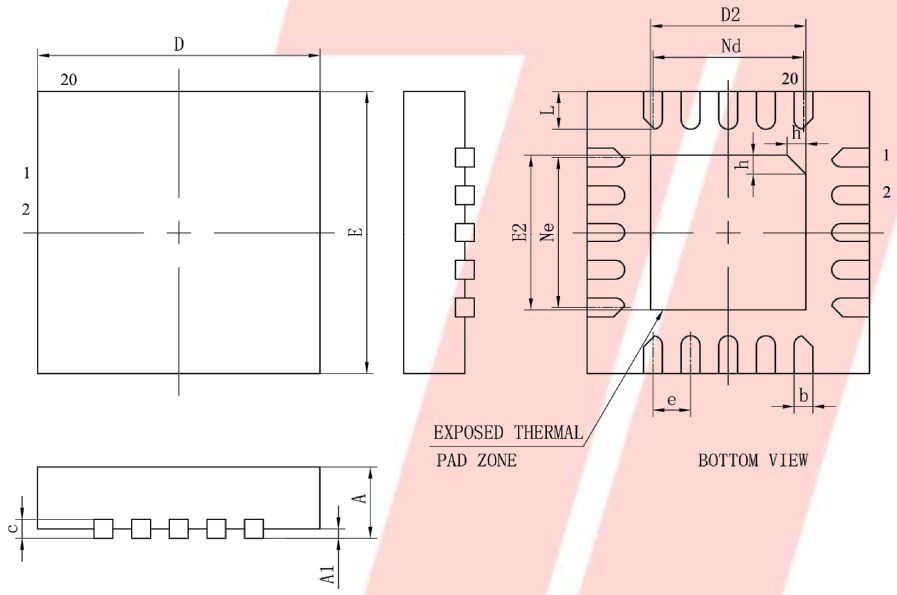
Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity			-92		dBm	
Co-channel Interference Rejection			-9		dB	
Adjacent Channel Interference Rejection	+1MHz		+5		dB	25℃, Power Supply VBAT=5V 2441MHz
	-1MHz		+2		dB	
	+2MHz		+37		dB	
	-2MHz		+36		dB	
	+3MHz		+40		dB	
	-3MHz		+35		dB	

Enhanced Data Rate **Table 3-9**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity			-92		dBm	
Co-channel Interference Rejection			-9		dB	
Adjacent Channel Interference Rejection	+1MHz		+5		dB	25℃, Power Supply VBAT=5V 2441MHz
	-1MHz		+2		dB	
	+2MHz		+37		dB	
	-2MHz		+36		dB	
	+3MHz		+40		dB	
	-3MHz		+35		dB	

4. Package Information

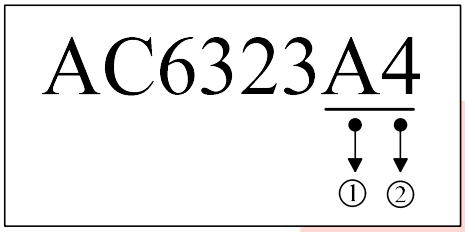
4.1 QFN20



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	—	0.02	0.05
b	0.15	0.20	0.25
c	0.18	0.20	0.25
D	2.90	3.00	3.10
D2	1.55	1.65	1.75
e	0.40BSC		
Ne	1.60BSC		
Nd	1.60BSC		
E	2.90	3.00	3.10
E2	1.55	1.65	1.75
L	0.35	0.40	0.45
h	0.20	0.25	0.30
L/F载体尺寸 (Mil)	75*75		

Figure 4-1 AC6323A_QFN20 Package

5. Package Type Specification



①Represents different packages

②Represents different memory sizes

2: 2Mbit Flash

4: 4Mbit Flash

6. Revision History

Date	Revision	Description
2021.03.06	V1.0	Initial Release